TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

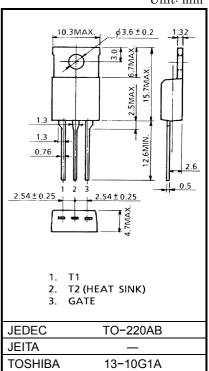
# SM6G45,SM6J45,SM6G45A,SM6J45A

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 400, 600V
- R.M.S ON–State Current
- $I_{T}$  (RMS) = 6A
- High Commutating (dv / dt)

### MAXIMUM RATINGS

CHARACTERI	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off- State Voltage	SM6G45 SM6G45A	VDRM	400	V	
	SM6J45 SM6J45A	V DRM	600		
R.M.S On-State Current (Full Sine Waveform Tc		I <sub>T (RMS)</sub>	6	А	
Peak One Cycle Surge On-State		l	60 (50Hz)	А	
Current (Non-Repetitive	)	ITSM	66 (60Hz)	A	
I <sup>2</sup> t Limit Value		l <sup>2</sup> t	18	A <sup>2</sup> s	
Critical Rate of Rise of C Current	)n−State	di / dt	50	Α / μs	
Peak Gate Power Dissip	ation	P <sub>GM</sub>	5	W	
Average Gate Power Dis	ssipation	P <sub>G (AV)</sub>	0.5	W	
Peak Gate Voltage		V <sub>GM</sub>	10	V	
Peak Gate Current		I <sub>GM</sub>	2	А	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature Ra	ange	T <sub>stg</sub>	-40~125	°C	



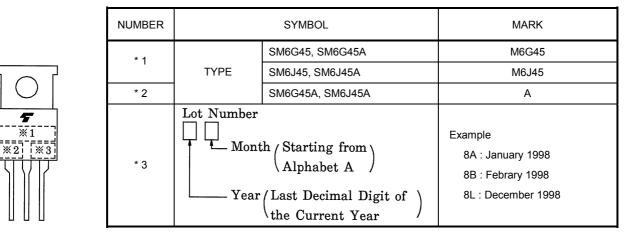
Weight: 2.0g

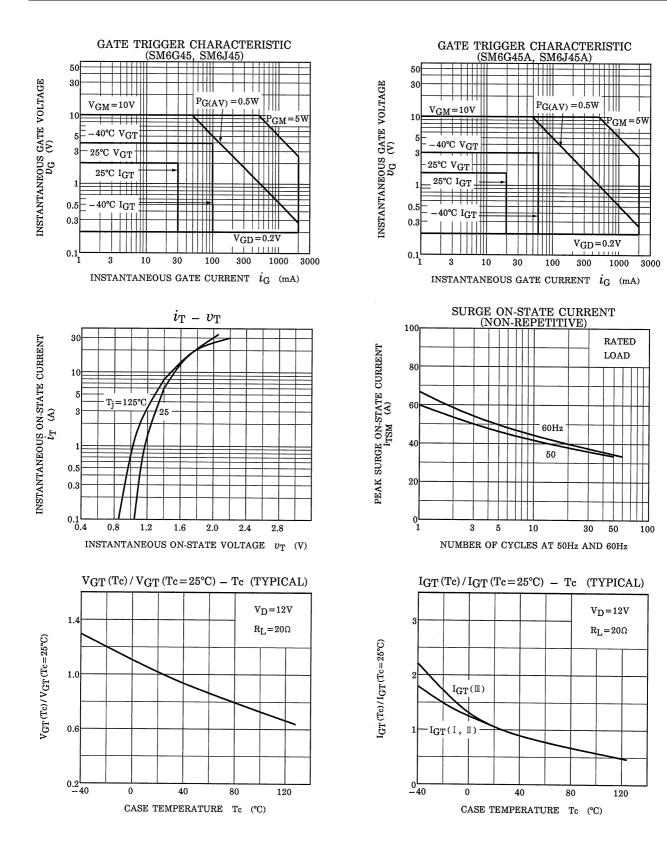
Unit: mm

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

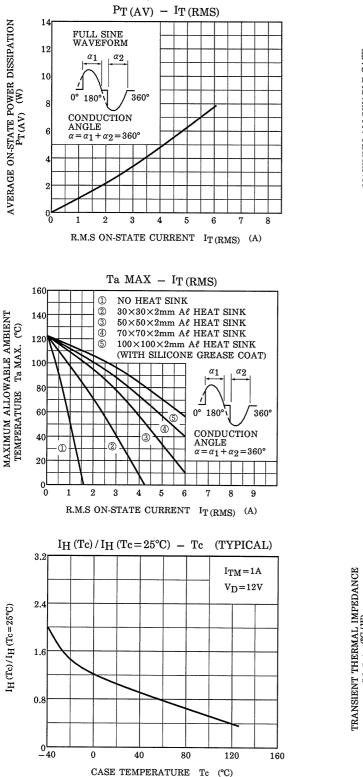
CHARACTERISTIC			SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I <sub>DRM</sub>	V <sub>DRM</sub> = Rated, T <sub>j</sub> = 125°C		_	_	2	mA		
Gate Trigger Voltage			I	V <sub>GT</sub>	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)	—	_	2	- V
	SM6G4	5	П			T2 (+), Gate (−)	_	_	2	
	SM6J45	5	III			T2 (−), Gate (−)	_	_	2	
			IV			T2 (-), Gate (+)	_	_	_	
			I			T2 (+), Gate (+)	_	_	1.5	
	SM6G4	5A	II			T2 (+), Gate (-)	_	_	1.5	
	SM6J45	БА	III			T2 (−), Gate (−)	_	_	1.5	
			IV			T2 (-), Gate (+)	_	_	_	
Gate Trigger Current			I	IGT	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)	_	_	30	- mA
	SM6G4	5	II			T2 (+), Gate (-)	_	_	30	
	SM6J45	5	III			T2 (−), Gate (−)	_	_	30	
			IV			T2 (-), Gate (+)	_	_	_	
			I			T2 (+), Gate (+)	_	_	20	
	SM6G4	5A	II			T2 (+), Gate (-)	_	_	20	
	SM6J45	A	III			T2 (−), Gate (−)	_	_	20	
			IV			T2 (-), Gate (+)	_	_	_	
Peak On-State Voltage			V <sub>TM</sub>	I <sub>TM</sub> = 9A		_	_	1.5	V	
Gate Non-Trigger Voltage			V <sub>GD</sub>	V <sub>D</sub> = Rated, Tc = 125°C		0.2	_	_	V	
Holding Current			IH	V <sub>D</sub> = 12V, I <sub>TM</sub> = 1A		_	_	50	mA	
Thermal Resistance			R <sub>th (j−c)</sub>	Junction to Case, AC		_	_	2.5	°C/W	
Critical Rate of Rise of Off- State Voltage at Commutation			(d) ( dt) -	V <sub>DRM</sub> = 400V, (di / dt) c = -3.3A / ms		10	_	_	V / µs	
				(dv / dt) c	$T_j = 125^{\circ}C$		4	—	—	v / µs

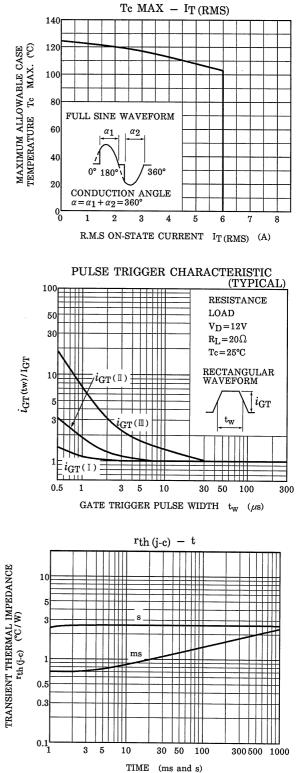
#### MARKING





# TOSHIBA





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